

SANYO Semiconductors DATA SHEET

N-channel Silicon Juncton FET

TF202FC — Electret Condenser Microphone Applications

Features

- · Ultrasmall package facilitates miniaturization in end products.
- · Especially suited for use in electret condenser microphone for audio equipments and telephones.
- · Excellent voltage characteristics.
- · Excellent transient characteristics.
- · Adoption of FBET process.
- · Halogen free compliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Gate-to-Drain Voltage	V _{GDO}		-20	V
Gate Current	IG		10	mA
Drain Current	ID		1	mA
Allowable Power Dissipation	PD		100	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Doromotor Sumb	Symbol	Conditions	Ratings			Unit
Parameter	Symbol		min	typ	max	UIIIL
Gate-to-Drain Breakdown Voltage	V(BR)GDO	IG=-100μA	-20			V
Cutoff Voltage	VGS(off)	V _{DS} =5V, I _D =1μA	-0.2	-0.6	-1.0	V

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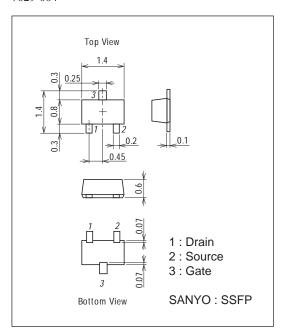
Parameter	Symbol	Conditions	Ratings			- Unit
Parameter			min	typ	max	Unit
Drain Current	IDSS	V _{DS} =5V, V _{GS} =0V	140*		350*	μΑ
Forward Transfer Admittance	yfs	V _{DS} =5V, V _{GS} =0V, f=1kHz	0.5	1.0		mS
Input Capacitance	Ciss	V _{DS} =5V, V _{GS} =0V, f=1MHz		3.5		pF
Reverse Transfer Capacitance	Crss	V _{DS} =5V, V _{GS} =0V, f=1MHz		0.65		pF
[Ta=25°C, V _{CC} =4.5V, R _L =1kΩ, Cin=15pF, See specified Test Circuit.]						
Voltage Gain	GV	V _{IN} =10mV, f=1kHz		-3.0		dB
Reduced Voltage Characteristic	ΔGVV	$V_{IN}=10$ mV, f=1kHz, $V_{CC}=4.5$ V $\rightarrow 1.5$ V		-1.2	-3.5	dB
Frequency Characteristic	ΔGvf	f=1kHz to 110Hz			-1.0	dB
Total Harmonic Distortion	THD	V _{IN} =30mV, f=1kHz		1.2		%
Output Noise Voltage	V _{NO}	V _{IN} =0V, A Curve			-110	dB

 * : The TF202FC is classified by IDSS as follows : (unit : $\mu\text{A}\text{)}$

Rank	4	5
I _{DSS}	140 to 240	210 to 350

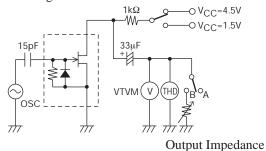
Package Dimensions

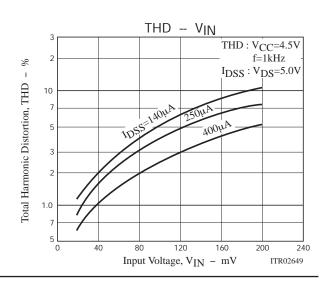
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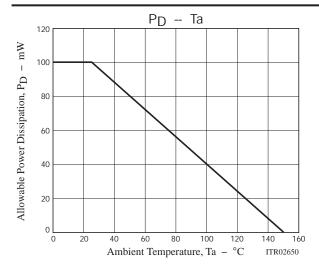


Test Circuit

Voltage gain Frequency Characteristic Distortion Reduced Voltage Characteristic







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